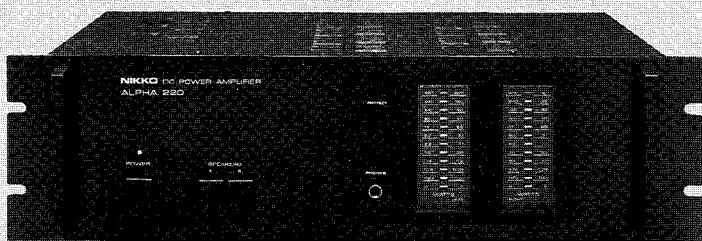


**NIKKO****POWER AMP**

# ALPHA 220

## STEREO POWER AMPLIFIER

### TYPE AND VOLTAGE

W-TYPE:	UL and CSA type	120V AC
E -TYPE:	NK-STD type	220V AC
B -TYPE:	BS type	240V AC

# SERVICE MANUAL

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# SPECIFICATIONS

## AMPLIFIER SECTION

### Continuous Power Output per Channel:

20 ~ 20000 Hz (8 ohms) . . . . .	more than 120 Watts
20 ~ 20000 Hz (4 ohms) . . . . .	more than 130 Watts
1000 Hz (8 ohms) . . . . .	more than 120 Watts
1000 Hz (4 ohms) . . . . .	more than 130 Watts

### T. H. Distortion, 8 ohms:

at Continuous Power Output . . .	no more than 0.008%
at 1 Watt Power Output . . . . .	no more than 0.02%

### T. H. Distortion, 4 ohms:

at Continuous Power Output . . .	no more than 0.02%
----------------------------------	--------------------

### I. M. Distortion, 8 ohms:

at Continuous Power Output . . .	no more than 0.01%
at 1 Watt Power Output . . . . .	no more than 0.02%

### IHF Power Bandwidth, 8 ohms: . . . . .

5 ~ 70000Hz

### Damping Factor at 1000 Hz, 8 ohms: . . . . .

more than 60

### Frequency Response, "NORMAL" input, 8 ohms:

at 1 Watt power Output . . . . .	10 ~ 100000Hz +0, -1dB
----------------------------------	------------------------

### Input Sensitivity for 120 Watts Power Output:

MAIN IN . . . . .	1V ± 2dB
-------------------	----------

### Signal to Noise Ratio, IHF "A" Network:

MAIN (NORMAL, DIRECT) . . . . .	better than 105dB
---------------------------------	-------------------

### Signal to Noise Ratio, DIN Filter:

MAIN IN (NORMAL, DIRECT) . . . . .	better than 90dB
------------------------------------	------------------

### Channel Balance: . . . . .

no more than 1dB

### Residual Hum and Noise, 8 ohms: . . . . .

no more than 0.5mV

### Idling Current: . . . . .

40 ~ 120mA

### Midpoint Voltage: . . . . .

0 ± 20mV

### Muting Delay Time: . . . . .

3 ~ 7 seconds

## GENERAL

### Power Requirement:

W-TYPE . . . . .	AC 120V, 60Hz
E-TYPE . . . . .	AC 220V, 50Hz
B-TYPE . . . . .	AC 240V, 50Hz

### Power Consumption: . . . . .

480 W (620 VA)

### Ambient Temperature during Operation: . . . . .

-10 ~ 30°C

### Dimensions:

Width . . . . .	482 mm (19 inches)
Height . . . . .	138 mm (5 1/3 inches)
Depth . . . . .	344 mm (13 1/2 inches)

### Weight, without package: . . . . .

13.5 kg (29.7 lbs)

\*Specifications are subject to change without notice.

# BLOCK DIAGRAM

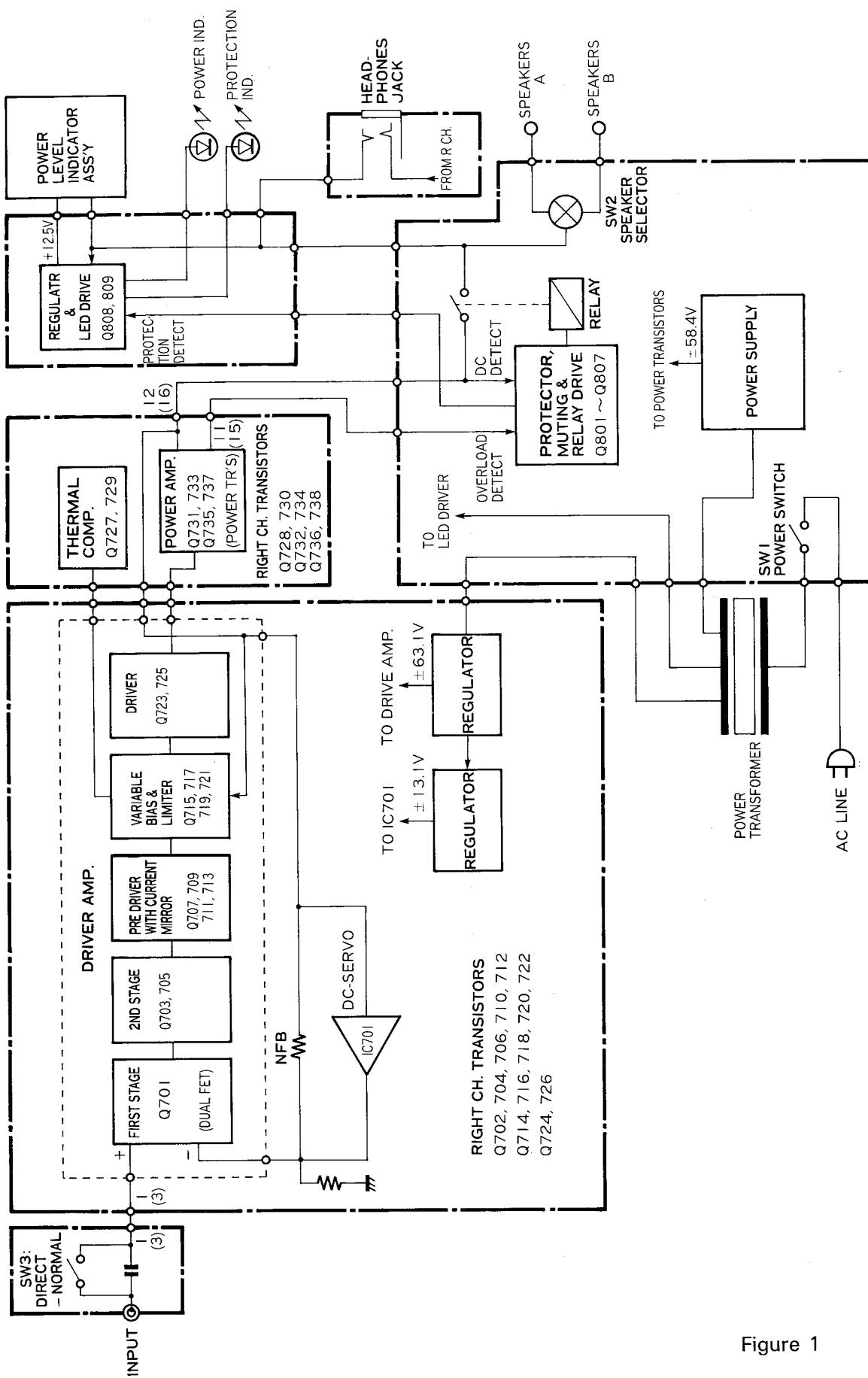


Figure 1

# DISASSEMBLY

## CABINET COVER REMOVAL

- Remove four tapping screws from the top of the unit.
- Remove four screws from both sides of the unit.
- Lift the cabinet cover away from the unit.

## BOTTOM PLATE REMOVAL

- Remove nine tapping screws from the bottom of the unit as shown in Photo 1. (#1 – #9)
- Lift the bottom plate away from the unit.

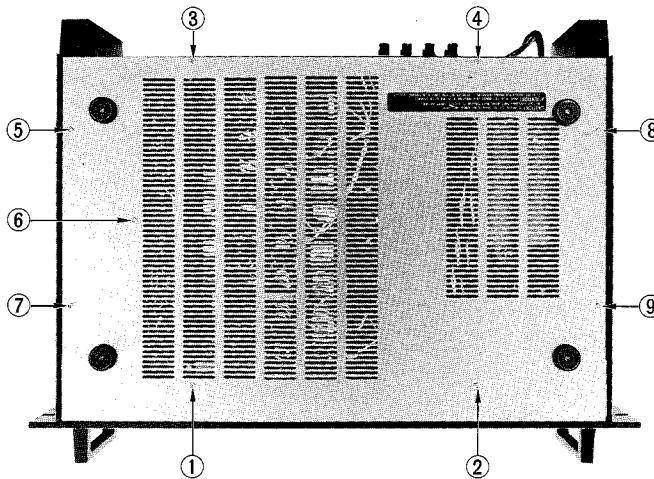


Photo 1

## FRONT PANEL REMOVAL

- Remove three tapping screws (#1 – #3) from the left side of the unit as shown in Photo 2.
- Similarly remove three tapping screws from the right side of the unit.
- Remove the front panel away from the unit by pulling it forward.

## POWER TRANSFORMER REMOVAL

- Remove the cabinet cover and the bottom plate.
- Disconnect all the cables from the power transformer.
- Remove four nuts (#1 – #4) from the chassis as shown in Photo 3.
- Lift the power transformer away from the unit.

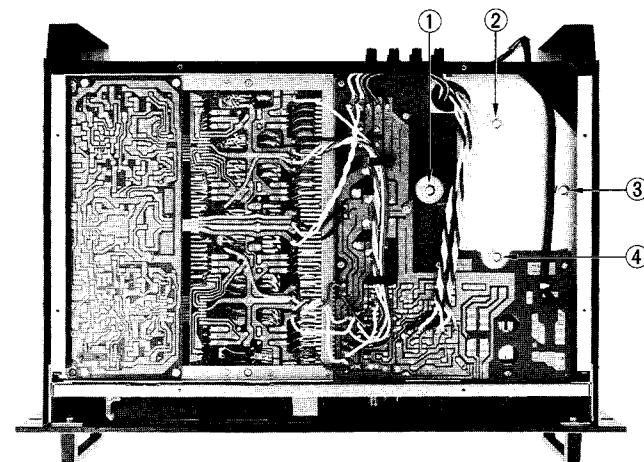


Photo 3

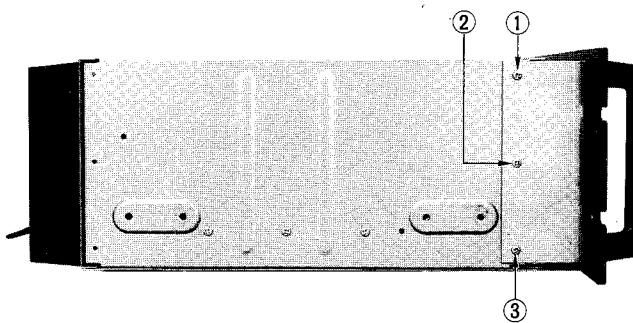


Photo 2

# CIRCUIT DESCRIPTION

NIKKO's ALPHA 220, adopting latest devices such as Hi-fT power transistors, is of a design introducing a variable bias circuit (non-switching circuit), a DC servo circuit and other most advanced techniques.

For details, refer to page 2 "BLOCK DIAGRAM" and page 8 "SCHEMATIC DIAGRAM".

The following are explanations of the main circuits and devices.

## 1. VARIABLE BIAS CIRCUIT

Currently, in the output stage of power amplifiers are mostly used SEPP (Single Ended Push Pull) circuits. (Fig. 2).

It is generally known that the current (idle current) flowing through NPN and PNP transistors of this circuit can be classified into three large groups of operation form, class "A", class "AB" and class "B". (Fig. 3).

In class "A" operation, neither of collector currents,  $Q_1$  and  $Q_2$ , becomes zero nor cut off. Even when the current flowing to the load  $R_L$  is zero, a certain current is flowing through  $Q_1$  and  $Q_2$ , and so no crossover distortion exists theoretically.

To realize perfect class "A" operation, however, a current equal to or more than maximum output should continue to be let flow at the output stage as idle current, causing class "A" operation to prove to

be a poor efficiency system.

In class "AB" or "B" operation, the  $Q_1$  plays the role of amplification of the plus part of the signal and  $Q_2$  that of the minus part, no matter whether idle current is large or small.

In other words, there definitely exists a period in which, when one transistor is on, the other transistor keeps cutting off, in these operations.

Switching distortion or crossover distortion is caused at the moment of this active status turning into cut-off status or the cut-off status into the active status. Nevertheless, as these operation forms have high efficiency with small idle current, it is much easier to use class "AB" or "B" operation for high power amplification rather than class "A".

A power amplifier enjoying the merit of each of these systems — that is, practically no crossover or switching distortion being caused in class "A" operation and easier high power amplification being achieved by class "B" — has been realized by adopting the variable bias circuit.

The idea of a variable bias circuit is that in no case the output stage is allowed to be cut-off by increasing and decreasing bias voltage in corresponding with the voltage of input signal.

Fig. 4 shows the variable bias circuit adopted in ALPHA 220.

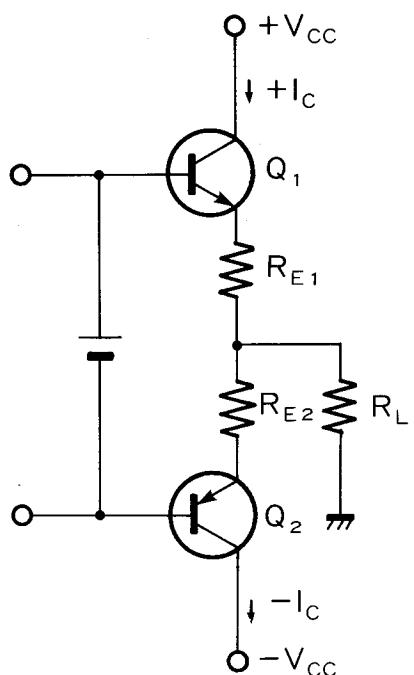


Figure 2 SEEP CIRCUIT

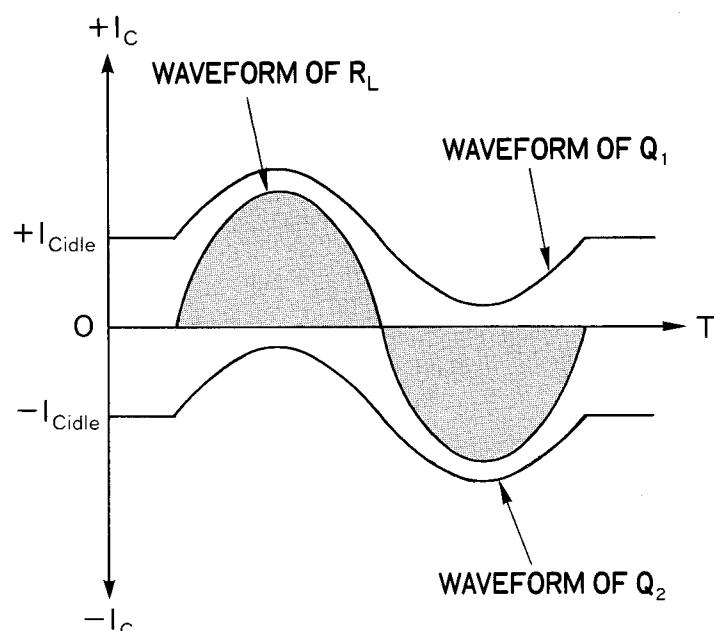


Figure 3-1 CLASS-A OPERATION

Now, suppose the plus wave (plus part) of signal has been inputted, the current of  $Q_{P1}$  increases and the voltage at both ends of  $R_{E1}$  become high, resulting in the voltage between (A) point and OUTPUT. At that time, the voltage at both ends of  $R_1$  becomes high because current flows  $R_1 \rightarrow D_1 \rightarrow Q_1$ , causing the potential at (C) point to lower and the voltage of  $Q_3$  between collector and emitter to rise.

As a result, the voltage between (A) and (B) rises and  $Q_{P2}$  is kept from being cut-off.

From another point of view, the voltage drops at the emitter resistor  $R_{E1}$  (these resistors are indispensable to protect transistors in stabilizing bias of the output stage or at the time of abnormal current flowing) is cancelled by the drop at  $R_1$ , thus protecting  $Q_{P2}$  from becoming zero or anti-bias.

In the same manner, when the minus wave (minus part) of signal has been inputted, current flows  $Q_2 \rightarrow D_2 \rightarrow R_2$ , resulting in a rise of  $V_{CE}$  at  $Q_4$  thus protecting  $Q_{P1}$  from being cut-off.

## 2. DC SERVO CIRCUIT

DC amplification is the most advanced form adopted for audio amplifiers as there is no phase lag over all the range from DC to audio frequency.

However, in a perfect DC amplifier (which is an amplifier having no coupling capacitors in its input part and NFB loop), a DC drift is caused in case a direct current is inputted or when the DC balance between each element has been lost due to temperature rise

inside the amplifier. The DC servo circuit is to suppress such a drift and realize a more stabilized amplifier.

The principle of a DC servo circuit is something like that of a comparator, in which changes in DC current between the output point and the ground is detected and drifts of the amplifier is controlled with their results used as the output of the servo circuit.

The basic elements are an integrating circuit composed of  $C_1$  and  $R_1$ , an operational amplifier and a mirror integrator composed of  $C_2$  and  $R_2$ . (Fig. 5).

Now, suppose a drift  $\Delta e_o$  has been caused at the output of the power amplifier, a potential with the same phase  $\Delta e_f$  is outputted at the output of the operational amplifier.

On the other hand, the initial stage of the power amplifier is a differential amplifier. When  $\Delta e_f$  is inputted at its inverting input, the potential at the non-inverting input  $\Delta e_i$  changes in the opposite direction of  $\Delta e_f$ , resulting in a decrease of drift at the output of the power amplifier.

The DC servo circuit has a specific frequency characteristic. In the range of DC and ultra low frequency, gain of the power amplifier is kept at one over several tens of decibel, and in the audio frequency band, amplification at a certain gain can be made in the same manner as ordinary power amplifier.

The frequency on which the DC servo circuit starts to have effects is determined by the four elements,  $C_1$ ,  $R_1$ ,  $C_2$  and  $R_2$ .

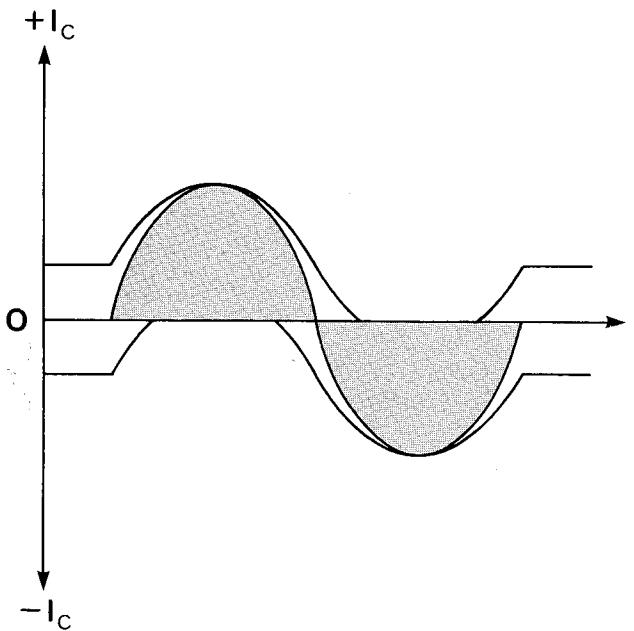


Figure 3-2 CLASS-AB OPERATION

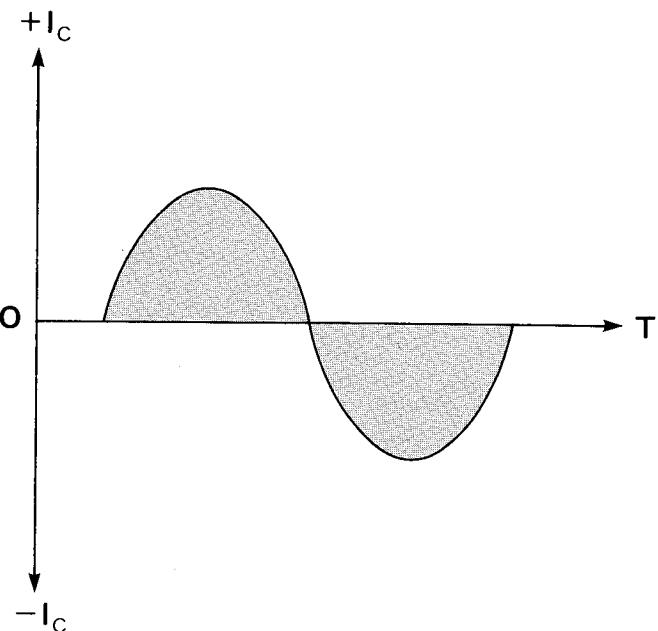


Figure 3-3 CLASS-B OPERATION

## PARTS LOCATION

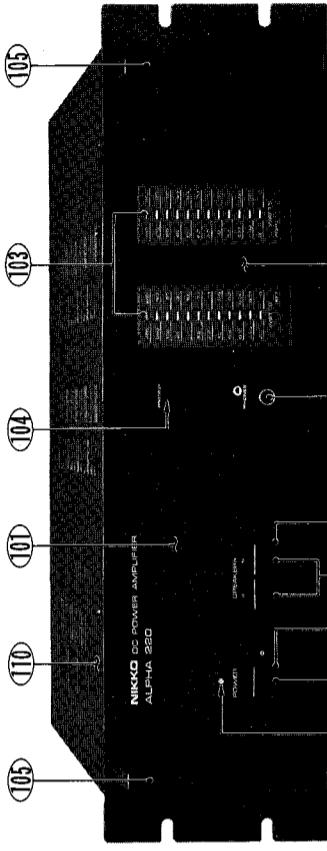


Photo 4

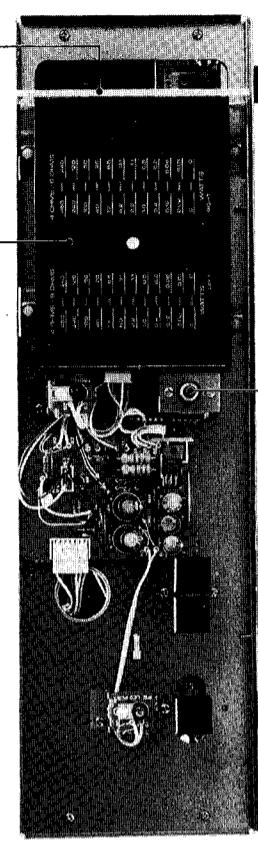


Photo 5

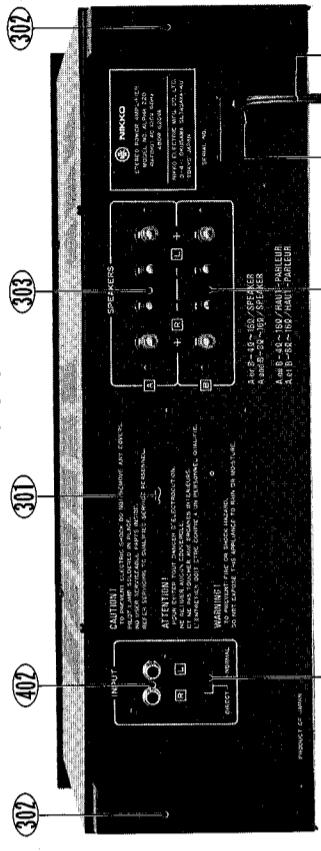


Photo 6

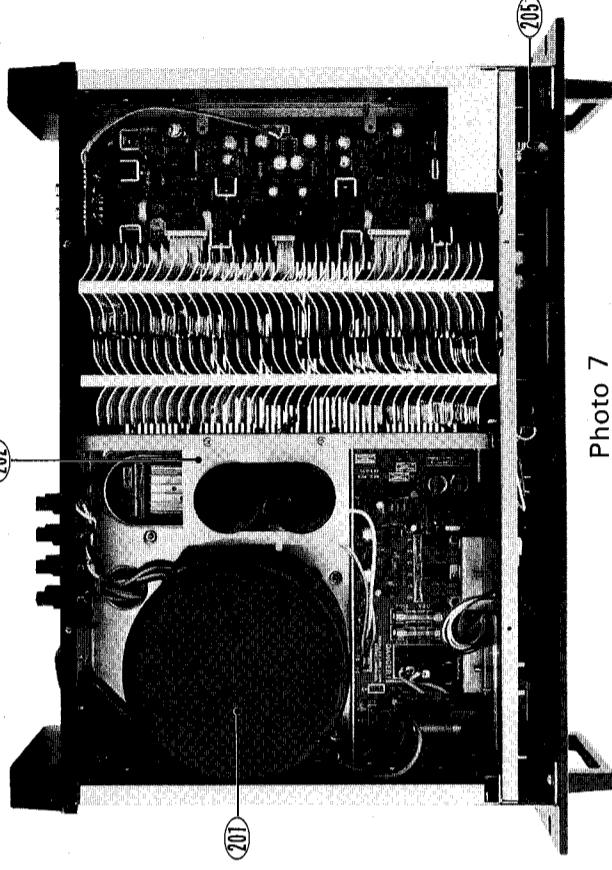


Photo 7

## 3. Hi-FT POWER TRANSISTORS

For details characteristics, refer to "SEMICONDUCTOR DATA" at the end of this manual.

The power transistors employed in ALPHA 220 realize an  $f_T$  (Current Gain-bandwidth Product) of 80 MHz with NPN type and 60 MHz with PNP type (each being a typical value) in spite of its high  $P_c$  (Collector Power Dissipation) such as 150 W (The value when  $T_c = 25^\circ\text{C}$ ). Compared with conventional transistors with a  $P_c$  of 150 W where  $f_T$  was around 10 MHz at maximum, the high speed attained by these Hi-FT power transistors is remarkable.

Such high  $f_T$  has been realized specially by the inside construction of these transistors which is greatly different from that of conventional ones — the multi-emitter construction.

In this construction, the emitter inside the transistor is divided into many units and emitter resistors with small resistance are inserted to each unit, resulting in a parallel connection.

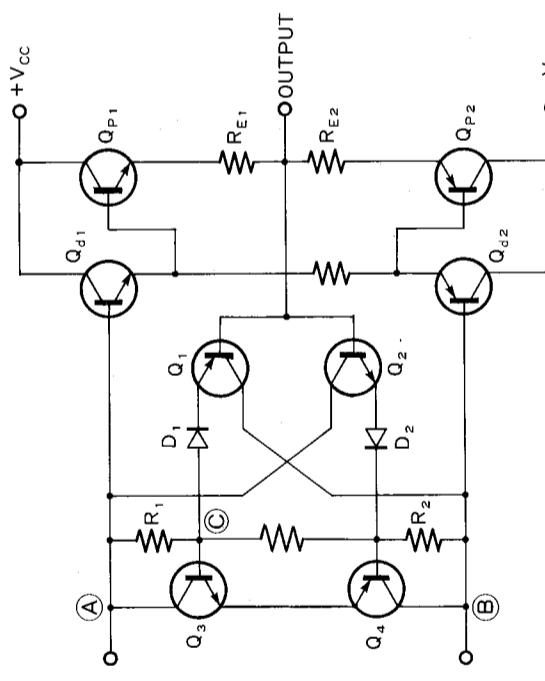


Figure 4 VARIABLE-BIAS CIRCUIT

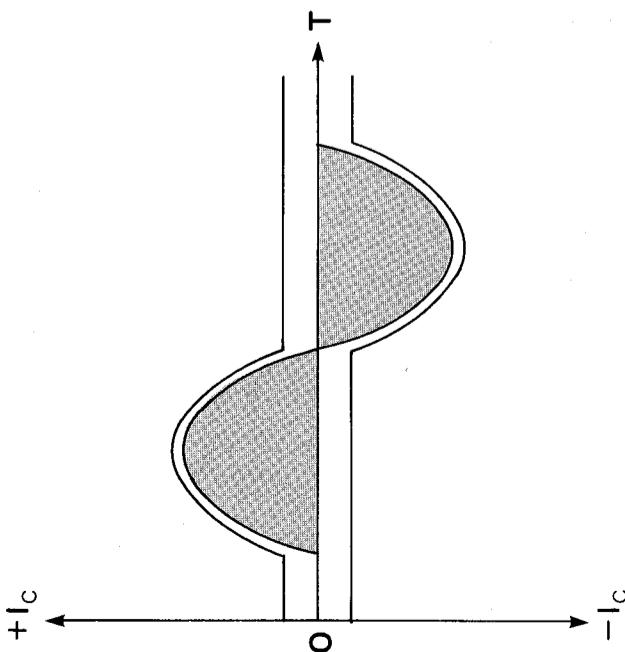


Figure 3-4 OPERATION OF BARIAVUE BIAS

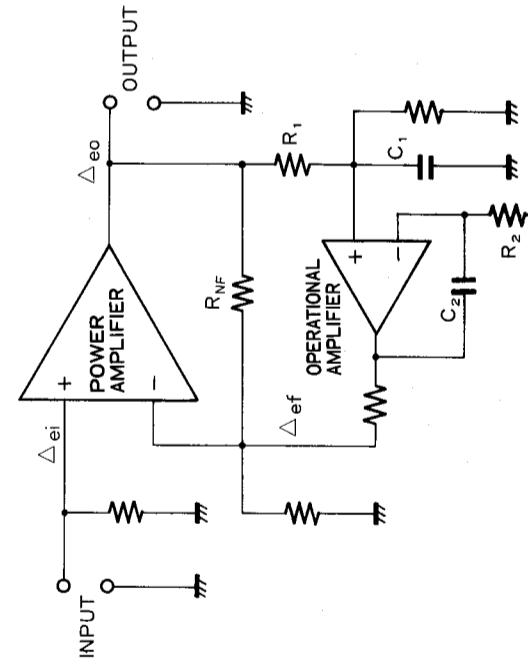


Figure 5 DC-SERVO CIRCUIT

# SCHEMATIC DIAGRAM

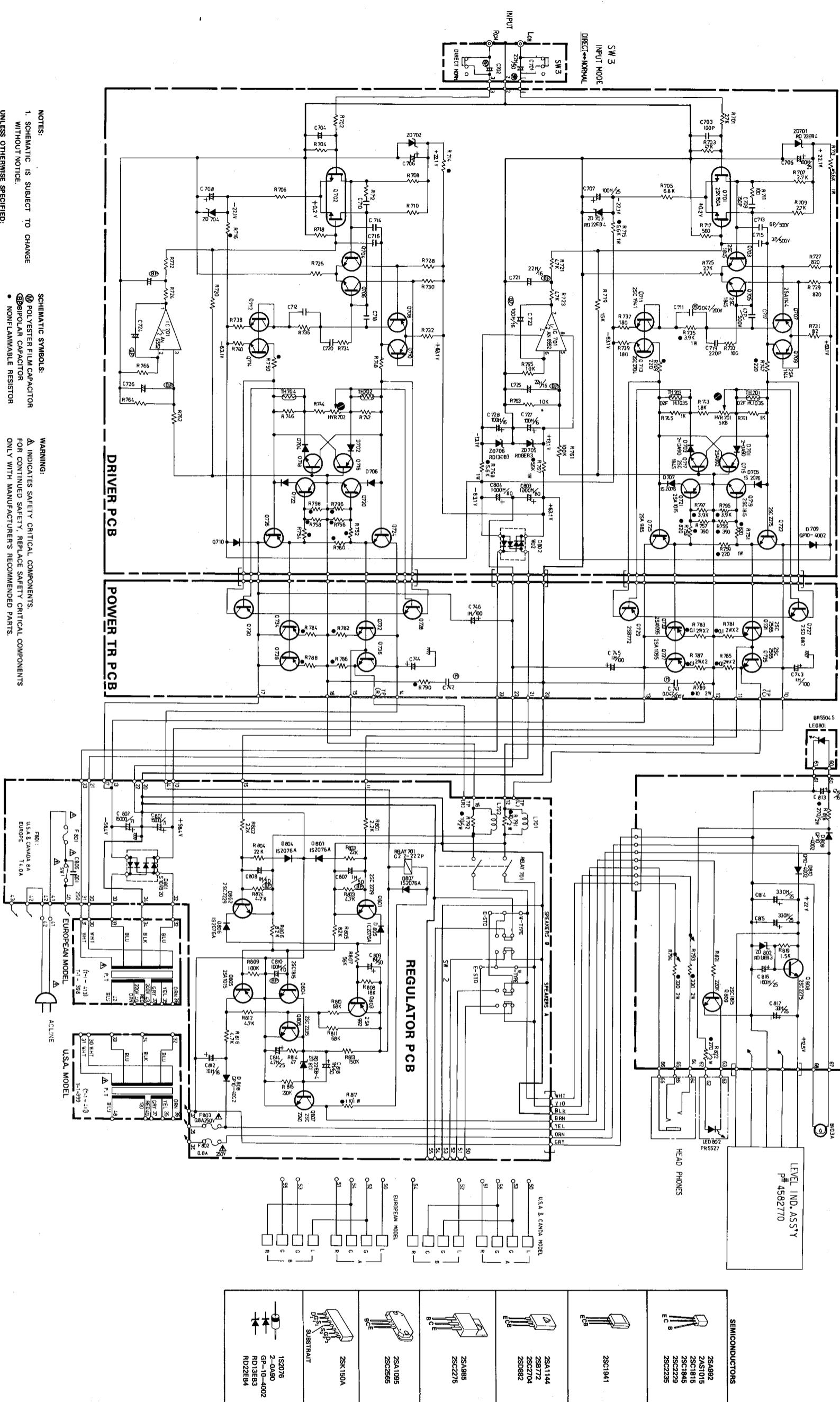
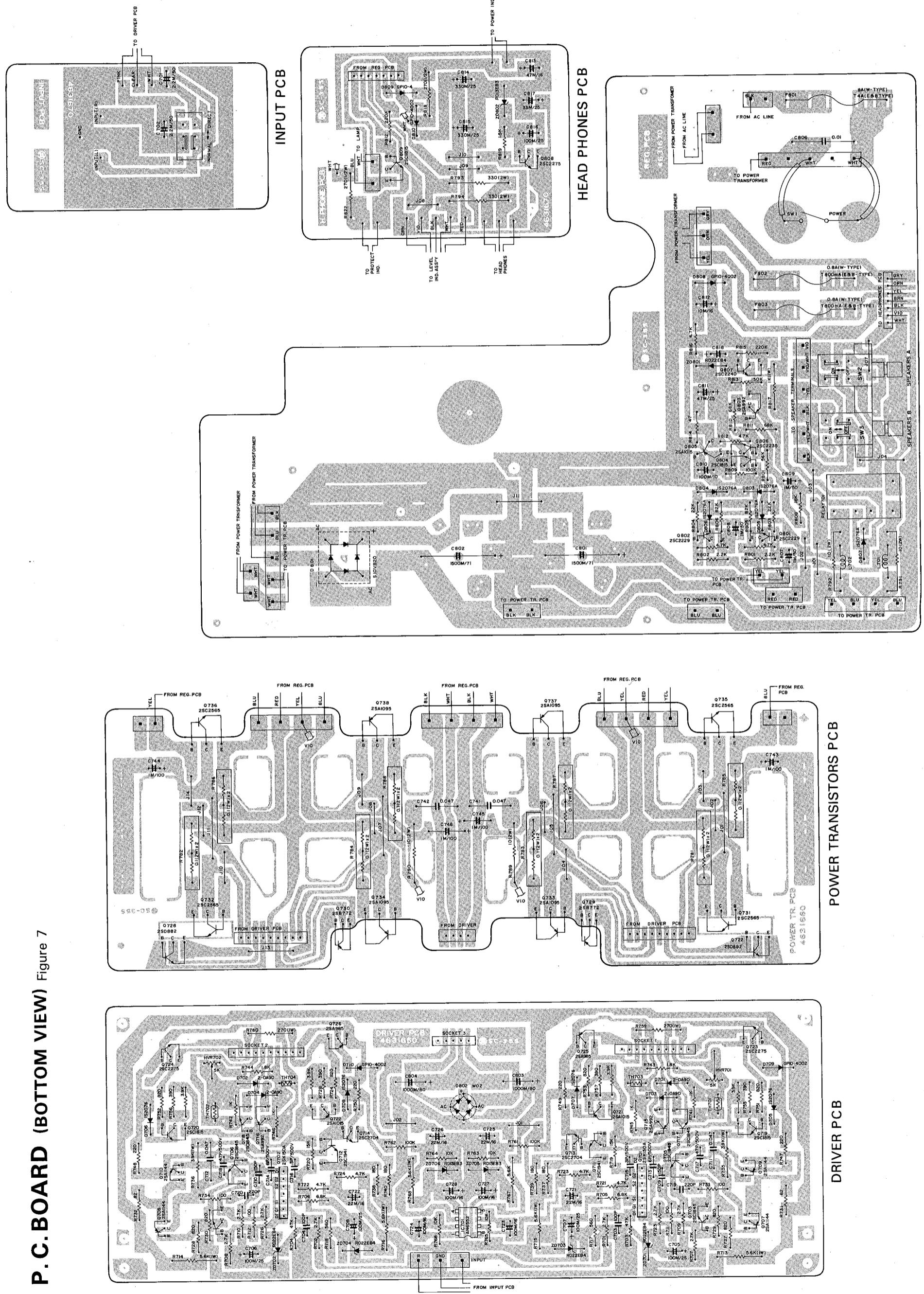


Figure 6

P.C. BOARD (BOTTOM VIEW) Figure 7



## ALIGNMENT

### ALIGNMENT PRECAUTIONS

- As the ALPHA 220 is a power amplifier with large output power, it consumes much electrical power and a great amount of current flows in the power source line of the primary side. Therefore, in the case when it is connected to the source by an extension cord, the size of the extension cord should be equal or larger than that of the power source cord of the ALPHA 220. Otherwise, the voltage might be reduced or the extension cord might generate excessive heat because of the resistance which the cord has, then not only can proper alignment be done, but also it is very dangerous.
- If the power sources are supplied to the ALPHA 220 and the instruments by branching off from one cord, the voltage is sometimes dropped down and the stability of the instruments goes down. The ALPHA 220 and the instruments should be connected to the power sources by using independent cords. The ALPHA 220 must take the power source from AC outlet of the wall side.
- As there are many parts which hold high voltages in the circuit and the parts inside of the ALPHA 220, be careful not to receive an electric shock. In the case of connecting and taking off the instruments, you must turn off the power switch of the ALPHA 220 before getting on the work.
- When the circuit happens to be shorted by the drivers or test probes used for alignment through mistake, the circuit and the parts will be damaged. As the damage is larger than that of ordinary amplifiers and receivers, close attention is needed. It is advised that the turning driver, excluding the top part, should be wrapped with insulation tape or a driver made of plastic or some kind of insulating material should be used.
- As the dummy load resistor generates heat while alignment, it gets very hot and you may be burnt if you touch it with bare hands. It is better if you can put the dummy load resistor in a place away from being touched, but the wire between the dummy load resistor and the amplifier should not be long. Contrive some method, like putting the dummy load resistor in a well ventilated box. Further, as more than 5 A current might flow in the wire connecting the dummy load resistor and the amplifier, at least the dummy load resistor and the amplifier, at least larger than AWG #18 thick wire should be used.
- All the adjustments in the following should be done after the slide switch on the rear panel is set in the "NORMAL" position.

### TEST EQUIPMENT

Allow a minimum of 10 minutes warm-up for test equipment.

Maintain rated line voltage.

Audio Frequency Generator  
Distortion Meter  
Oscilloscope

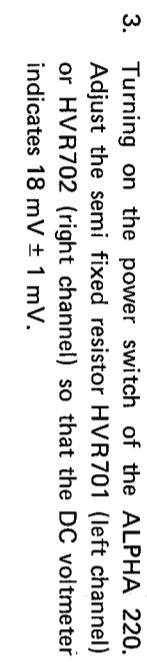
AC Voltmeter  
DC Voltmeter

2-Dummy Load Resistors, 8 ohms, 250 W

All the semi fixed resistors of the MAIN AMP PCB are set around the center position temporarily. (HVR701 and HVR702.)

### IDLING CURRENT ADJUSTMENT

- Connect the 8 ohms dummy load resistors to the left and right channel speaker terminals.
- Connect the DC voltmeter across the wiring terminal No. 12 and "TP-L" (left channel) or No. 16 and "TP-R" (right channel). (see Photo 8)
- Turning on the power switch of the ALPHA 220. Adjust the semi fixed resistor HVR701 (left channel) or HVR702 (right channel) so that the DC voltmeter indicates  $18 \text{ mV} \pm 1 \text{ mV}$ .
- Turn off the power switch of the ALPHA 220 and remove the DC voltmeter.



### METER CIRCUIT ADJUSTMENT

NOTE: See illustration, Figure 8, for test equipment hook-up.

- Connect 8 ohms dummy load resistors to the left and right channel speaker terminals.
- Connect the AC voltmeter, distortion meter and the oscilloscope to the left (right) channel speaker terminals. Connect the generator to left (right) channel input terminal.
- Turning on the power switch of the ALPHA 220.
- Set the frequency of the generator to 1 KHz. Adjust the output level of the generator so as to make the output power 98 W. (28 V AC voltmeter reading.)
- Adjust the semi-fixed resistors of the POWER LEVEL INDICATOR PCB so that the LED of "120 W" dimly lights up.
- Turning off the power switch of the ALPHA 220.
- Remove all test equipment.

Figure 8 TEST EQUIPMENT HOOK-UP

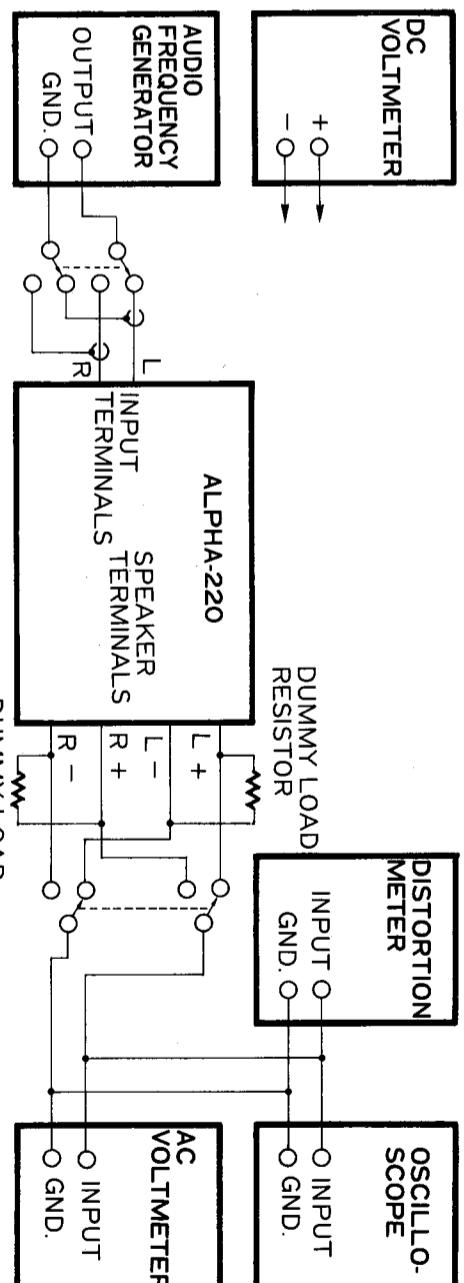
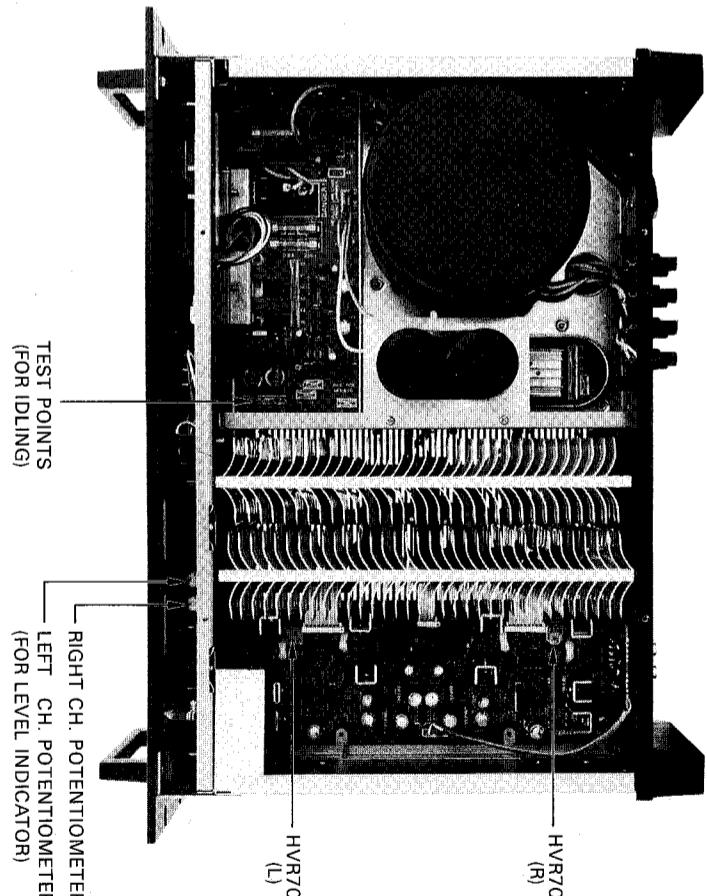


Photo 8 ADJUSTMENT POINTS

# POWER TRANSISTORS MOUNTING ASSEMBLY

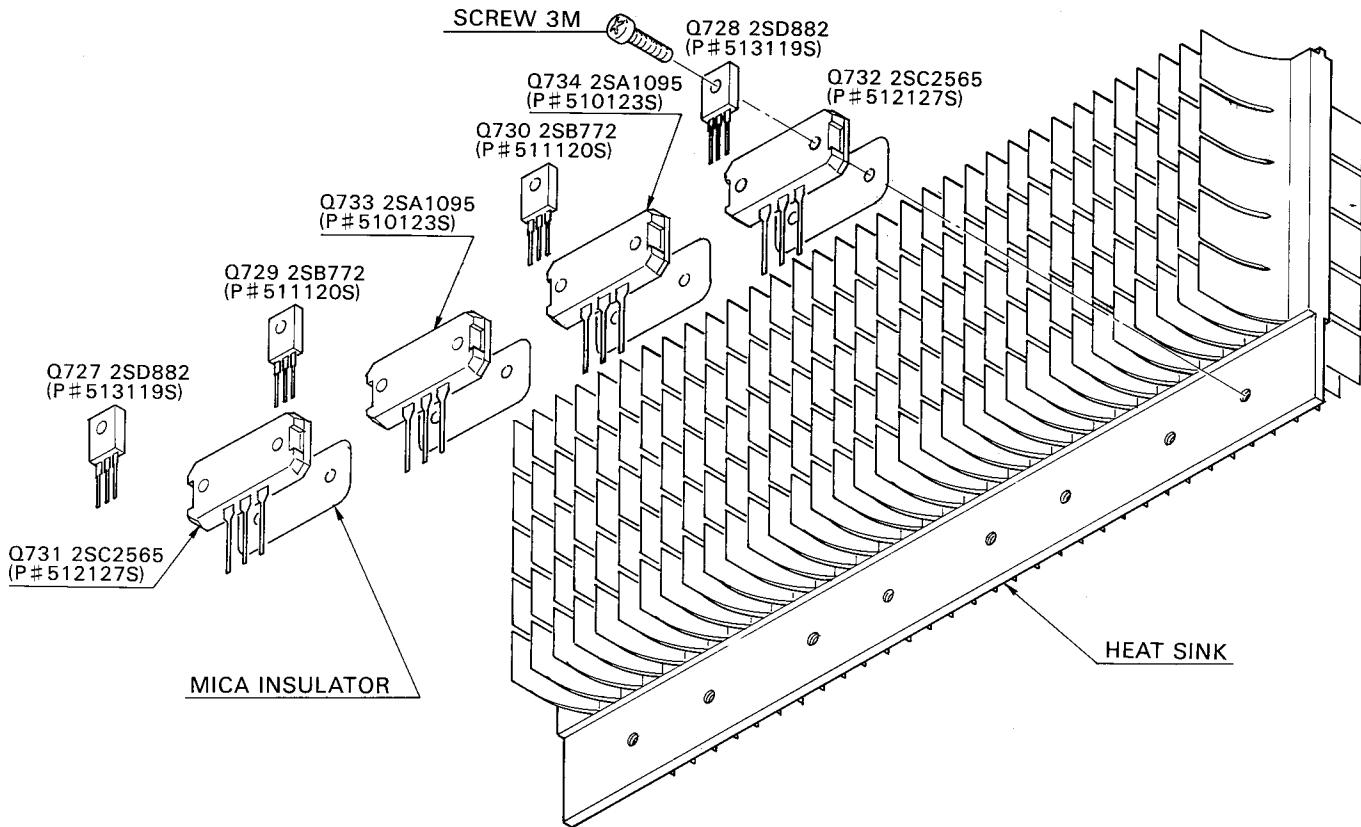


Figure 9

**NOTE:** For best heat conduction, use thermally conductive silicon grease between the power transistor and the mica insulator and between the insulator and the heat sink.

## PRECAUTIONS FOR REPAIR SERVICE

Many of these items are included just as a reminder — they are normal procedures for experienced technicians. Short-cuts can be taken: but, often they cause additional damage to transistors, circuit components or the printed circuit board.

1. **Do not** bridge electrolytic capacitors with AC power. The resultant surges may damage solid state devices.
2. **Do not** bias the base of any transistor while voltage is being applied to its collector.

3. Replacements for output and driver transistors, if necessary, must be made from the same hfe group as the original type. Be sure to include this information when ordering replacement transistors.
4. If one output transistor burns out (open or shorts), always remove all output transistors in that channel and check the bias adjustment, the control and other parts in the network with an ohmmeter before inserting a new transistor. All output transistors in one channel will be destroyed if the base biasing circuit is open in the emitter end.

# PARTS LIST

1. \* The KEY NUMBER (#) marked with a (\*) on parts list relate to number of three digits with a ( ). (Photo 4 ~ 7)
2. + Numerals in file indicate the quantity of parts used in one type.
3. ++ TR : Transistor  
FET : Field effect transistor  
VR : Volume control (Variable resistor)  
RES : Carbon film fixed resistor  
MO-RES : Metal oxide film fixed resistor  
CEM-RES : Cemented wirewound fixed resistor  
FP : Flame proof  
C-CAP : Ceramic capacitor  
E-CAP : Aluminum electrolytic capacitor  
M-CAP : Polyester film capacitor  
S-CAP : Polystyrene film capacitor  
T-CAP : Tantalum electrolytic capacitor  
BP-CAP : Bipolar electrolytic capacitor  
LC-CAP : Low current leakage electrolytic capacitor.

4. Assemblies and parts are subject to change without notice.

5. Parts ordering procedure:

- A. DO NOT USE THE "KEY" NUMBER AND "SYMBOL" NUMBER.  
(these are control # for the factory only)

B. Include in any order

- a. Part number.  
b. Part description.  
c. Model number.

(any of the above lacking from an order may delay shipment of that order.)

CAUTION:

The △ mark, the KEY NO. and the SYMBOL NO. circled with rectangle in the schematic diagram and the shaded area in the parts list designate components which have special characteristics important for safety and should be replaced only with types identical to those in the original circuit or specified in the parts list.

KEY NO.	SYMBOL NO.	TYPE <sup>+</sup> WEB	DESCRIPTION <sup>++</sup>	PART NO.
PACKING MATERIALS & ACCESSORIES				
001	1 1 1	Carton box	9825790	
002	2 2 2	Pad	9840970	
003	1 1 1	Sack, polyethylen cloth	9640740	
004	1 1 1	Sack, polyethylen cloth - #13	9640320	
005a	1 --	Manual, instructions - English and French	960340E	
005b	- 1 1	Manual, instructions - in five different languages	960340K	
006	1 --	Manual, safety instructions	9670410	
007a	1 --	Card, warranty - U.S.A.	967043A	
007b	1 --	Card, warranty - Canada	9670420	
008	1 --	List, service stations	9690210	
009	1 1 1	Cord, RCA phono pin plug - 2T-1	962014A	
CABINET ASSEMBLY				
★101a	1 1 1	Panel, front - SILVER	7885060	
★101b	1 1 1	Panel, front - BLACK	7885050	
★102a	1 1 1	Panel, power level indicator - SILVER	7870540	
★102b	1 1 1	Panel, power level indicator - BLACK	7870490	
★103	1 1 1	Window, power level indicator	7802650	
★104	1 1 1	Globe, LED - protection indicator	7402540	
★105a	2 2 2	Handle - 100G - SILVER	7490180	
★105b	2 2 2	Handle - 100B - BLACK	7490190	
★106	1 1 1	Guide, button - 1P18 - power switch	7402550	
★107	1 1 1	Guide, button - 2P18 - speakers selector	7402560	
★108	1 1 1	Globe, LED - input power indicator	7402120	
★109a	3 3 3	Button, push - M18GL - power/speakers, SILVER	7852290	
★109b	3 3 3	Button, push - M18BK - power/speakers, BLACK	7852300	
★110	1 1 1	Cover, top	7821110	
111	1 1 1	Plate, bottom	7326430	
112	4 4 4	Foot, polyethylen - 22φx10	7401350	
CHASSIS ASSEMBLY				
△★201a	1 --	Transformer, power - T-1-397 - AC 120V	1103970	
△★201b	- 1 1	Transformer, power - T-1-413 - AC220 or 240V	1104130	
★202	1 1 1	Supporter, filter capacitors	7002510	
203	1 1 1	Power level indicator assembly	4582770	
★204	1 1 1	Inside panel, power level indicator	7802660	
★205	1 1 1	Light guide, level indicator	7401580	
206	1 1 1	Lamp - 8V 0,3A	5808210	
BACK PLATE ASSEMBLY				
★301a	1 --	Plate, back - (W)	7326390	
★301b	- 1 1	Plate, back - (E)	7326400	
★302	2 2 2	Block, terminal guard	7401860	
★303	2 2 2	Terminal, speakers - screw type 4P	4450480	

KEY NO.	SYMBOL NO.	TYPE <sup>+</sup> WEB	DESCRIPTION <sup>++</sup>	PART NO.				
MAIN AMP PC BOARD ASSEMBLY								
(POWER OUTPUT SECTION)								
△★304a	1 --	Cord, AC line - SPT-1	606010A					
△★304b	- 1 --	Cord, AC line - CEE-2T	600508A					
△★304c	-- 1	Cord, AC line - BS	600515A					
△★305a	1 --	Bush, power cord - SR-3P-4	7400620					
△★305b	- 1 1	Bush, power cord - SR-4N-4	7400690					
(DRIVER PCB SECTION)								
Q727,728	2 2 2	TR 2SD882 (P or Q)	513119S					
Q729,730	2 2 2	TR 2SB772 (P or Q)	511120S					
Q731,732,								
Q735,736	4 4 4	TR 2SC2565 (O or R)	512127S					
Q733,734,								
Q737,738	4 4 4	TR 2SA1095 (O or R)	510123S					
C741,742	2 2 2	M-CAP 0.047uf 10% 400V	273473K					
C743								
~ C746	4 4 4	E-CAP 1uf 100V	211810Q					
R781								
~ R788	8 8 8	CEM-RES 0.1ohm 2Wx2	382109P					
R789,790	2 2 2	FP-MO-RES 10ohm 2W	362100L					
IC701	1 1 1	IC AN6552	518096S					
Q701,702	2 2 2	FET 2SK 150A (GR)	516038S					
Q703								
~ Q706	4 4 4	TR 2SC1845 (E or F)	512115S					
Q707								
~ Q710	4 4 4	TR 2SA1144 (O or Y)	510120S					
Q711,712	2 2 2	TR 2SC1941 (L or K)	512112S					
Q713,714	2 2 2	TR 2SC2704 (O or Y)	512122S					
Q715,716	2 2 2	TR 2SA992 (E or F)	510110S					
Q717,718	2 2 2	TR 2SC1845 (E or F)	512115S					
Q719,720	2 2 2	TR 2SC1815 (Y or GR)	512107S					
Q721,722	2 2 2	TR 2SA1015 (Y or GR)	510102S					
Q723,724	2 2 2	TR 2SC2275 (P or Q)	512120S					
Q725,726	2 2 2	TR 2SA985 (P or Q)	510118S					
D701								
~ D704	4 4 4	Diode 2-0A90	500013G					
D705								
~ D708	4 4 4	Diode 1S2076	501019S					
D709,710	2 2 2	Diode GP10-4002	560066S					
D802	1 1 1	Diode W02	560061S					
ZD701								
~ ZD704	4 4 4	Zener diode RD22EB4	502059S					
ZD705,706	2 2 2	Zener diode RD13EB3	502063S					
TH701								
~ TH704	4 4 4	Thermistor D2FHL-103S	5400180					

PART ORDERING PROCEDURE ----- DO NOT USE THE "KEY" NUMBER AND "SYMBOL" NUMBER. (these are control # for the factory only.) Include in any order: a. Part number, b. Part description, c. Model number. (any of the above lacking from an order may delay shipment of the order.)

KEY	SYMBOL	TYPE <sup>+</sup>	DESCRIPTION <sup>++</sup>				PART
NO.	NO.	W E B					NO.
C703,704	2 2 2	C-CAP 100pf	10%	50V		232101K	
C705							
~ C708	4 4 4	E-CAP 100uf	25V			211330Q	
C709,710	2 2 2	C-CAP 150pf	10%	50V		232151K	
C711,712	2 2 2	M-CAP 0.047uf	10%	200V		272473K	
C713,714	2 2 2	C-CAP 6pf	10%	500V		234609K	
C715,716	2 2 2	C-CAP 3pf	10%	500V		234309K	
C717,718	2 2 2	C-CAP 47pf	10%	500V		234470K	
C719,720	2 2 2	C-CAP 100pf	10%	500V		234101K	
C721,722	2 2 2	BP-CAP 22uf	16V			215222N	
C723,724	2 2 2	BP-CAP100uf	16V			215230N	
C725,726	2 2 2	BP-CAP 22uf	16V			215222N	
C727,728	2 2 2	E-CAP 100uf	16V			211230Q	
C803,804	2 2 2	E-CAP 1000uf	80V			2100130	
HVR701							
~ 702	2 2 2	Potentiometer 5kohm				4301410	
R701,702	2 2 2	RES 2.7kohm	5%	1/4W		328272J	
R703,704	2 2 2	RES 47kohm	5%	1/4W		328473J	
R705,706	2 2 2	RES 6.8kohm	5%	1/4W		328682J	
R707							
~ R710	4 4 4	RES 2.7kohm	5%	1/4W		328272J	
R711,712	2 2 2	RES 100ohm	5%	1/4W		328101J	
R713							
~ R716	4 4 4	FP-MO-RES 5.6kohm	5%	1W		361562L	
R717,718	2 2 2	RES 560ohm	5%	1/4W		328561J	
R719,720	2 2 2	RES 15kohm	5%	1/4W		328153J	
R721							
~ R724	4 4 4	RES 4.7kohm	5%	1/4W		328472J	
R725,726	2 2 2	RES 2.7kohm	5%	1/4W		328272J	
R727							
~ R730	4 4 4	RES 820ohm	5%	1/4W		328821J	
R731,732	2 2 2	RES 820hm	5%	1/4W		328820J	
R733,734	2 2 2	RES 100ohm	5%	1/4W		328101J	
R735,736	2 2 2	FP-MO-RES 3.9kohm	5%	1W		361392L	
R737							
~ R740	4 4 4	RES 180ohm	5%	1/4W		328181J	
R741,742	2 2 2	RES 1kohm	5%	1/4W		328102J	
R743,744	2 2 2	RES 1.8kohm	5%	1/4W		328182J	
R745,746	2 2 2	RES 1kohm	5%	1/4W		328102J	
R747							
~ R750	4 4 4	FP-RES 220ohm	5%	1/4W		328221L	
R751							
~ R754	4 4 4	FP-RES 820ohm	5%	1/4W		328821L	
R755							
~ R758	4 4 4	FP-RES 390ohm	5%	1/4W		328391L	
R759,760	2 2 2	FP-MO-RES 270ohm	5%	1W		361271L	
R761,762	2 2 2	RES 100kohm	5%	1/4W		328104J	
R763							
~ R766	4 4 4	RES 10kohm	5%	1/4W		328103J	
R767,768	2 2 2	FP-MO-RES 5.6kohm	5%	1W		361562L	
<b>REGULATOR PC BOARD ASSEMBLY</b>							
<b>(REGULATOR SECTION)</b>							
F801	1 —	Fuse – 8A 250V MGC				4700760	
F802,803	2 —	Fuse – 0.8A 250V MGC				4700580	
F801	-1 1	Midget fuse – T4.0A 250V				4720400	
F802,803	-1 1	Midget fuse – T0.8A 250V				4720320	
SW1	1 —	Switch, push – SDZ-1P TV-8 – power				4041500	
SW1	-1 1	Switch, push – ESB-90179S – power				4041600	
D801	1 1 1	Diode S10VB20				5600585	
C801,802	2 2 2	E-CAP 15000uf 71V				2100120	
C806	1 —	M-CAP 0.01uf 125V				284103M	
C806	-1 1	M-CAP 0.01uf 250V				283103M	
<b>(PROTECTOR SECTION)</b>							
SW2, 3	1 1 1	Switch, twin push – SUF-24 – speakers				4041590	
RELAY1	1 1 1	Relay – G2Z-222P – DC24V				1700300	
<b>(HEADPHONES PCB SECTION)</b>							
★401	1 1 1	Jack, headphones				4550260	
Q808	1 1 1	TR 2SC2275 (P or Q)				512120S	
Q809	1 1 1	TR 2SC1815 (Y or GR)				512107S	
D809,810	2 2 2	Diode GP10-4002				560066S	
ZD801	1 1 1	Zener diode RD13EB3				502063S	
C813	1 1 1	E-CAP 47uf 16V				211225Q	
C814,815	2 2 2	E-CAP 330uf 25V				211333Q	
C816	1 1 1	E-CAP 100uf 25V				211330Q	
C817	1 1 1	E-CAP 33uf 25V				211323Q	
<b>(INPUT PCB SECTION)</b>							
R793,794	2 2 2	FP-MO-RES 330ohm	5%	2W		362331L	
R818	1 1 1	FP-RES 270ohm	5%	1/4W		329271L	
R819	1 1 1	RES 1.5kohm	5%	1/4W		328152J	
R821	1 1 1	RES 220kohm	5%	1/4W		328224J	
R822	1 1 1	FP-RES 270ohm	5%	1/4W		329271L	
<b>(POWER INDICATOR SECTION)</b>							
C701,702	2 2 2	BP-CAP 2.2uf 50V				215512N	
<b>(PROTECTION INDICATOR SECTION)</b>							
LED801	1 1 1	LED BR5504S				5060300	
LED801	1 1 1	Spacer, LED				7903140	
<b>(PROTECTION INDICATOR SECTION)</b>							
LED802	1 1 1	LED PR5527S				5060270	
LED802	1 1 1	Spacer, LED				7903110	

# SEMICONDUCTOR DATA

## TRANSISTORS

† NOTES  
Ge: Germanium  
Si: Silicon

A: Alloy  
B: Base  
D: Diffused  
Dd: Double-diffused  
Df: Drift-field  
E: Epitaxial  
G: Grown  
J: Junction  
M: Mesa  
P: Planer  
Pc: Point-contact  
Td: Triple-diffused

DEVICE TYPE	APPLICATIONS	STRUCTURE†	MAXIMUM RATINGS Absolute-Maximum Values: (TA = 25°C unless otherwise specified)					ELECTRICAL CHARACTERISTICS Typical Values: (TA = 25°C unless otherwise specified)										MANUFACTURER			
			Collector-to-Base Voltage V <sub>CBO</sub> (V)	Emitter-to-Base Voltage V <sub>EBO</sub> (V)	Collector Current I <sub>C</sub> (mA)	Collector-Dissipation PC (mW)	Junction Temperature T <sub>J</sub> (°C)	Collector Cutoff Current I <sub>CBO</sub> (uA)	V <sub>cB</sub> (V)	h <sub>FE</sub>	V <sub>CE</sub> (V)	I <sub>C</sub> (mA)	V <sub>CE(sat)</sub> (V)	I <sub>C</sub> (mA)	IB (mA)	f <sub>T</sub> (MHz)	V <sub>CE</sub> (V)	I <sub>E</sub> (mA)	I <sub>C*</sub> (mA)	Output Capacitance Cob (pF)	Others
2SA985 (P, Q)	AF, Power amp.	PNP Si-E	-120	-5	-1.5A	25W (Tc=25°C)	150	-1 max.	-120	100 ~ 320	-5	-300	-2 max.	-1A	-100	180	-5	-200*	29	Complementary to 2SC2275	NEC
2SA992 (E, F)	AF, Low noise	PNP Si-E	-120	-5	-50	500	125	-0.05 max.	-120	300 ~ 800	-6	-0.1	-0.3 max.	-10	-1	100	-6	1	3 max.	Complementary to 2SC1845	NEC
2SA1015 (Y, GR)	AF, General	PNP Si-E	-50	-5	-150	400	125	-0.1 max.	-50	120 ~ 400	-6	-2	-0.3 max.	-100	-10	80 min.	-10	-1*	7 max.	Complementary to 2SC1815	TOSHIBA
2SA1095 (O, R)	AF, Power amp.	PNP Si-E	-160	-5	-15A	150W (Tc=25°C)	150	-50 max.	-160	55 ~ 160	-5	-1A	-2 max.	-5A	-500	60	-10	-1A*	350	Complementary to 2SC2565	TOSHIBA
2SA1144 (O, Y)	AF, Driver	PNP Si-E	-150	-5	-50	10W (Tc=25°C)	150	-0.1 max.	-150	80 ~ 240	-5	-10	1 max.	-10	-1	120	-5	-10*	2.5	Complementary to 2SC2704	TOSHIBA
2SB772 (P, Q)	AF, Power amp.	PNP Si-E	-40	-5	-3A	1W	150	-1 max.	-30	100 ~ 320	-2	-20	-0.5 max.	-2A	-200	80	-5	100	55	Complementary to 2SD862	NEC
2SC1815 (Y, GR)	AF, General	NPN Si-E	60	5	150	400	125	0.1 max.	60	120 ~ 400	6	2	0.25 max.	100	10	80 min.	10	1*	3 max.	Complementary to 2SA1015	TOSHIBA
2SC1845 (E, F)	AF, Low noise	NPN Si-E	120	5	50	500	125	0.05 max.	120	300 ~ 800	6	0.1	0.3 max.	10	1	110	6	-1	2.5 max.	Complementary to 2SA992	NEC
2SC1941 (L, K)	AF, Driver	NPN Si-E	160	5	50	800	150	0.1 max.	160	135 ~ 400	10	1	0.6 max.	20	2	120	10	-10	3 max.		NEC
2SC2229 (O, Y)	AF, Driver	NPN Si-Td	200	5	50	800	150	0.1 max.	200	70 ~ 240	5	10	0.5 max.	10	1	120	30	10*	5 max.		TOSHIBA
2SC2235 (O, Y)	AF, Driver	NPN Si-E	120	5	800	900	150	1 max.	120	80 ~ 240	5	100	1 max.	500	50	120	5	100*	30 max.		TOSHIBA
2SC2240 (GR, BL)	AF, Low Noise	NPN Si-E	120	5	100	300	125	0.1 max.	120	200 ~ 700	6	2	0.3 max.	10	1	100	6	1*	3		TOSHIBA
2SC2275 (P, Q)	AF, Power amp.	NPN Si-E	120	5	1.5A	25W (Tc=25°C)	150	1 max.	120	100 ~ 320	5	300	2 max.	1A	100	200	5	200*	19	Complementary to 2SA985	NEC
2SC2565 (O, R)	AF, Power amp.	NPN Si-E	160	5	15A	150W (Tc=25°C)	150	50 max.	160	55 ~ 160	5	1A	2 max.	5A	500	80	10	1A*	200	Complementary to 2SA1095	TOSHIBA
2SC2704 (O, Y)	AF, Driver	NPN Si-E	150	5	50	10W (Tc=25°C)	150	0.1 max.	150	80 ~ 240	5	10	1 max.	10	1	200	5	10*	1.8	Complementary to 2SA1144	TOSHIBA
2SD882 (P, Q)	AF, Power amp.	NPN Si-E	40	5	3A	1W	150	1 max.	30	100 ~ 320	2	20	0.5 max.	2A	200	90	5	-100	45	Complementary to 2SB772	NEC

## FIELD EFFECT TRANSISTOR

DEVICE TYPE	APPLICATIONS	STRUCTURE†	MAXIMUM RATINGS Absolute-Maximum Values: (TA = 25°C unless otherwise specified)					ELECTRICAL CHARACTERISTICS Typical Values: (TA = 25°C unless otherwise specified)										MANUFACTURER		
			Gate-to-Drain Source Voltage V <sub>GDO</sub> (V)	Gate-to-Source Voltage V <sub>GSO</sub> (V)	Gate Current I <sub>G</sub> (mA)	Drain Current I <sub>D</sub> (mA)	Total Dissipation P <sub>D</sub> (mW)	Channel Temperature T <sub>ch</sub> (°C)	Gate Leak Current Test Conditions IGSS (nA)	Gate to Drain Breakdown Voltage V <sub>BRD</sub> (GDO) (V)	Drain Current Test Conditions IDSS (mA)	Gate to Source Cutoff Voltage V <sub>GSS (off)</sub> (V)	Forward Transfer Admittance Test Conditions  M <sub>fe</sub>   (mS)	Feed Back Capacitance Test Conditions C <sub>rss</sub> (pF)	Power Gain (Common Source) Test Conditions G <sub>PS</sub> (dB)	Noise Figure Test Conditions NF (dB)				
			V <sub>DS</sub> =-30V	V <sub>GS</sub> =-30V	V <sub>DS</sub> =0	I <sub>D</sub> =1 max.			V <sub>DS</sub> =10V	V <sub>GS</sub> =0	I <sub>D</sub> =2.6 mA	V <sub>GS</sub> =-6.5V	V <sub>DS</sub> =10V	V <sub>GS</sub> =0 f=1 kHz	I <sub>D</sub> =3mA	V <sub>DS</sub> =10V	V <sub>GS</sub> =0 f=1 kHz			
2SK150 A (GR)	AF, Low noise Differential amp.	Si N-channel junction (Dual)	-50	-50	10		200/ unit	125										V <sub>DS</sub> =10V R <sub>g</sub> =1 kΩ I <sub>D</sub> =1 mA f=1 kHz	2 max.	TOSHIBA

## DIODES, LED'S

DEVICE TYPE	APPLICATIONS	STRUCTURE†	MAXIMUM RATINGS Absolute-Maximum Values: (TA = 25°C unless otherwise specified)								ELECTRICAL CHARACTERISTICS Typical Values: (TA = 25°C unless otherwise specified)								MANUFACTURER
			Reverse Surge Voltage V <sub>Rsurge</sub> (V)	Peak Reverse Voltage VR (V)	Reverse Voltage VR (V)	Peak Forward Voltage VF (V)	Average Rectified Current IF (mA)	Forward Surge Current IO (mA)	Junction Temperature T <sub>J</sub> (°C)	Total Power Dissipation P <sub>D</sub> (mW)	Forward Current IFmin (mA)	Forward Voltage VF (V)	Forward Voltage Test Condition VF (V)	Reverse Current IRmax (mA)	Reverse Current Test Condition VR (V)	Others			
			V <sub>Rsurge</sub> =15	V <sub>Rsurge</sub> =450	V <sub>Rsurge</sub> =150	V <sub>Rsurge</sub> =150	1	175	250		4	1							
2-0A90	Detector	Ge-Pc																MATSUSHITA	
1S2076	Medium speed Switching	Si-EP	35	30		450	150	1	175	250				0.8	10	1	30	HITACHI	
1S2076A	Medium speed Switching	Si-EP	70	60		450	150	1	175	250				0.8	10	1	30	HITACHI	
GP10 -4002	Rectifier	Si-DJ	100	70				1A	30	175				1.1	1A	5		GENERAL INSTRUMENT	
W02	Rectifier	Si-DJ (Bridge)			200	200		1.5A	50	125				1.0	1A	10		R <sub>th</sub> = 50°C/W	GENERAL INSTRUMENT
S10VB20	Rectifier	Si-DJ (Bridge)			200			10A	200	150				1.05		10			SHINDENGEN
BR5504S	Lamp (red)	GaAlAs			4		300	I <sub>F</sub> = 50		85	100			2.0	20	100	4	I <sub>V</sub> = 80 mcd (I <sub>F</sub> = 20 mA)	STANLEY
PR5527S	Lamp (red)	GaP			4		100	I <sub>F</sub> = 30		85	75			2.0	10	100	4	I <sub>V</sub> = 1.2 mcd (I <sub>F</sub> = 10 mA)	STANLEY

## ZENER DIODES

DEVICE TYPE	APPLICATIONS	STRUCTURE†	MAXIMUM RATINGS Absolute-Maximum Values: (TA = 25°C unless otherwise specified)					ELECTRICAL CHARACTERISTICS Typical Values: (TA = 25°C unless otherwise specified)										MANUFACTURER	
			Total Power Dissipation P <sub>D</sub> (mW)	Zener Current I <sub>Z</sub> (A)	Junction Temperature T <sub>J</sub> (°C)	Zener Voltage V <sub>Z</sub> (V)			Differential Resistance R <sub>Z</sub> (Ω)		Temperature Coefficient $\gamma_Z$ (°C)		Reverse Current I <sub>Z</sub> (mA)		Reverse Current Test Conditions I <sub>Z</sub> (mA)		Others		
			MIN (V)	Typ (V)	Max (V)	I <sub>Z</sub> (mA)	TYP (Ω)	Max (Ω)	I <sub>Z</sub> (mA)	TYP (%)	Max (%)	I <sub>Z</sub> (mA)	Max (mA)	I <sub>Z</sub> (mA)	Max (mA)	V <sub>R</sub> (V)			
RD13EB3	Regulator	Si-J	400		175	12.99			13.66	10		25	10				2	10	NEC
RD22EB4	Regulator	Si-J	400		175	21.52			22.63	5		60	5				2	17	NEC

## INTEGRATED CIRCUITS AN6552

- Manufacturer: MATSUSHITA
- Applications: Dual Operational Amplifier

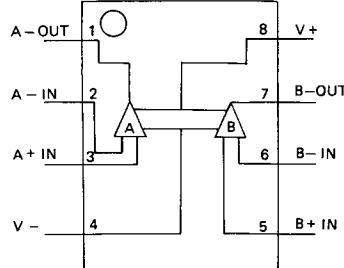
### ABSOLUTE MAXIMUM RATINGS

Supply Voltage . . . . .	$\pm 18\text{ V}$	Input Voltage . . . . .	$\pm 15\text{ V}$
Internal Power Dissipation . . . . .	500 mW	Storage Temperature Range . . . . .	-40°C to +125°C
Differential Input Voltage . . . . .	$\pm 30\text{ V}$	Operating Temperature Range . . . . .	-20°C to +75°C

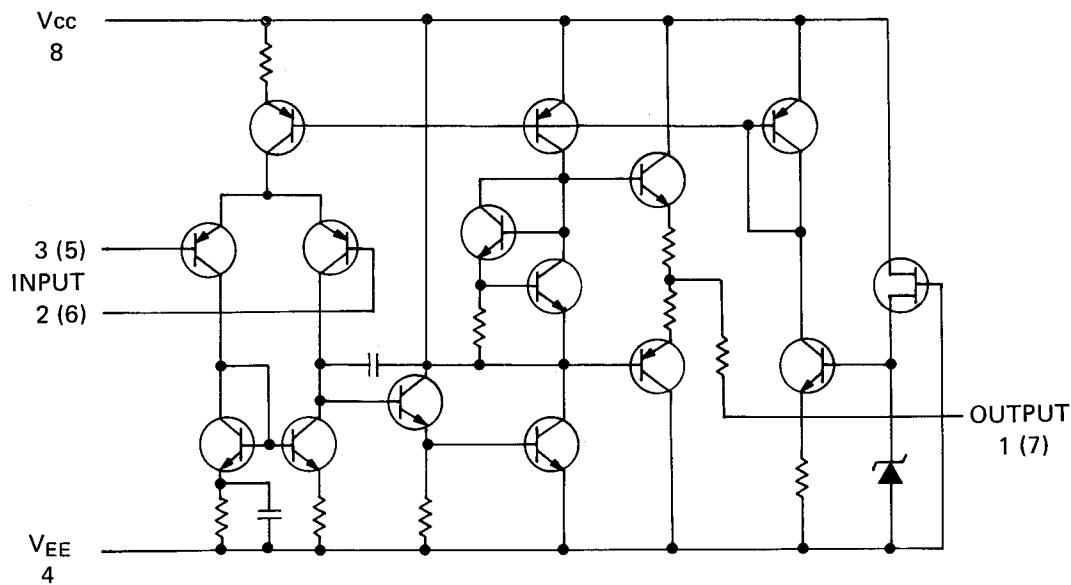
ELECTRICAL CHARACTERISTICS ( $V_{CC} = \pm 15\text{V}$ ,  $T_A = +25^\circ\text{C}$  unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$		0.5	6.0	mV
Input Offset Current			5	200	nA
Input Bias Current				500	nA
Large-Signal Voltage Gain	$R_L \geq 2\text{ k}\Omega$ $V_{out} = \pm 10\text{V}$	86	100		dB
Output Voltage Swing	$R_L \geq 2\text{ k}\Omega$	$\pm 10$	$\pm 13$		V
Common Mode Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 10\text{ k}\Omega$		30	150	$\mu\text{V/V}$
Slew Rate	$R_L \geq 2\text{ k}\Omega$		1		$\text{V}/\mu\text{s}$

### TERMINAL GUIDE (TOP VIEW)



### SCHEMATIC DIAGRAM (1/2 CIRCUIT)



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L.A. OFFICE

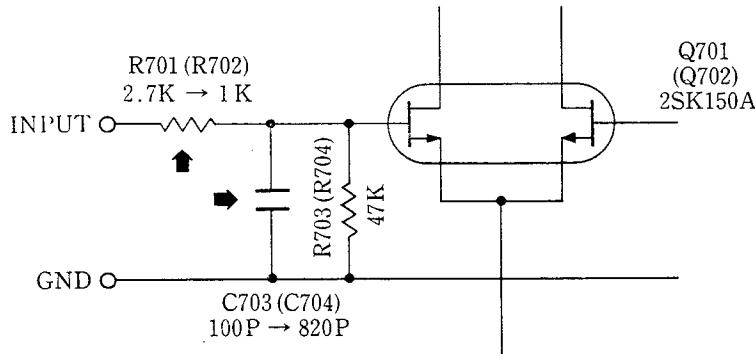
16270 Raymer St., Van Nuys, Ca. 91406, U.S.A.

**NIKKO****SERVICE DATA**NO. 81-001  
DATE May 15, 1981***Important Information for your Parts and Service Department*****MODEL: ALPHA 220****ASSEMBLY: DRIVER PCB**

For the purpose of protecting the transistors in the power stage, replace capacitors and resistors on the DRIVER P.C. BOARD.

1. Capacitors C703 and C704 (100 pf) are replaced with new ones (820 pf).
2. Resistors R701 and R702 (2.7 kohms) are replaced with new ones (1 kohms).

These modifications are already done for the units bearing Serial No. C6534701 and up.

**PARTS LIST**

DELETE		
SYMBOL No.	DESCRIPTION	PART No.
C703, 704	Ceramic capacitor 100pf 10% 50V	232101K
R701, 702	Carbon film resistor 2.7 kohms 5% ¼W	328272J

ADD		
SYMBOL No.	DESCRIPTION	PART No.
C703, 704	Ceramic capacitor 820pf 10% 50V	232821K
R701, 702	Carbon film resistor 1 kohms 5% ¼W	328102J

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